TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

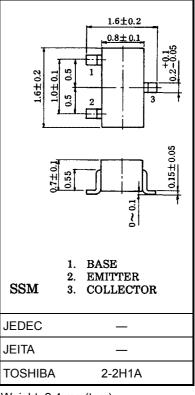
2SC5108

For VCO Application

Unit: mm

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V_{CBO}	20	V	
Collector-emitter voltage	V _{CEO}	10	V	
Emitter-base voltage	V _{EBO}	3	V	
Base current	Ι _Β	15	mA	
Collector current	Ic	30	mA	
Collector power dissipation	PC	100	mW	
Junction temperature	Tj	125	°C	
Storage temperature range	T _{stg}	−55~125	°C	



Weight: 2.4 mg (typ.)

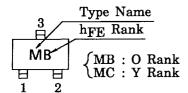
Electrical Characteristics (Ta = 25°C)

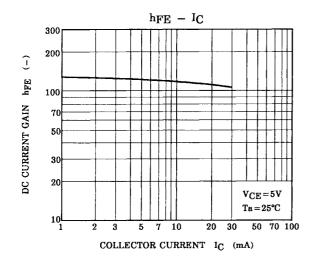
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = 10 \text{ V}, I_{E} = 0$	_	_	0.1	μΑ
Emitter cut-off current	I _{EBO}	V _{EB} = 1 V, I _C = 0	_	_	0.1	μА
DC current gain	h _{FE} (Note 1)	V _{CE} = 5 V, I _C = 5 mA	80	_	240	
Transition frequency	f _T	$V_{CE} = 5 \text{ V}, I_{C} = 5 \text{ mA}$	4	6	_	GHz
Insertion gain	S _{21e} ²	$V_{CE} = 5 \text{ V}, I_{C} = 5 \text{ mA}, f = 1 \text{ GHz}$	7	11	_	dB
Output capacitance	C _{ob}	V _{CB} = 5 V, I _F = 0, f = 1 MHz (Note 2)	_	0.7	_	pF
Reverse transfer capacitance	C _{re}	$V_{CB} = 5 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$ (Note 2)	_	0.5	0.9	pF
Collector-base time constant	C _c .rbb'	$V_{CB} = 5 \text{ V}, I_{C} = 3 \text{ mA}, f = 30 \text{ MHz}$	_	5.5	10	ps

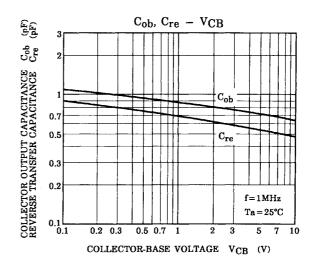
Note 1: hFE classification O: 80~160, Y: 120~240

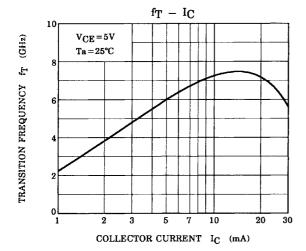
Note 2: C_{re} is measured by 3 terminal method with capacitance bridge.

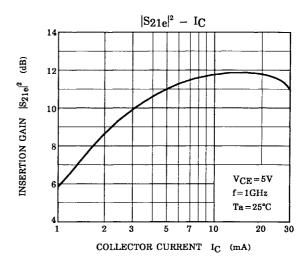
Marking

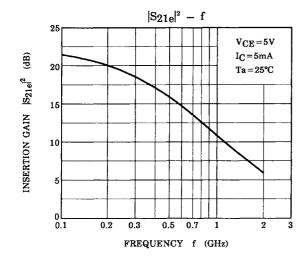


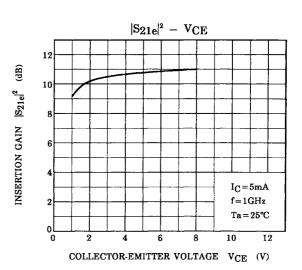


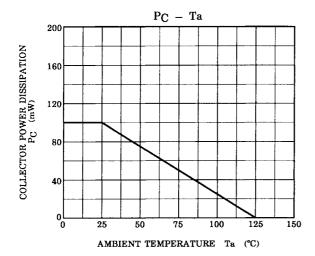












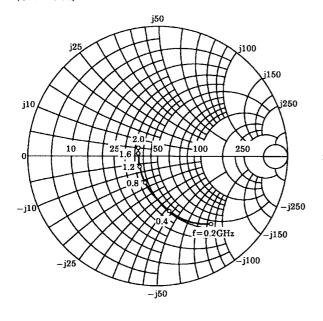
S-Parameter $Z_O = 50 \Omega$, $Ta = 25^{\circ}C$

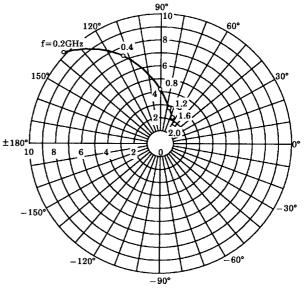
$V_{CE} = 5 V$, $I_C = 5 mA$

Frequency	S	11	S2	21	S1	12	S2	22
(MHz)	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.
200	0.684	-47.0	10.116	136.8	0.049	63.1	0.765	-29.5
400	0.438	-79.2	7.260	112.9	0.072	56.5	0.553	-37.8
600	0.301	-101.2	5.388	99.1	0.090	56.5	0.452	-39.1
800	0.226	-119.2	4.227	90.0	0.107	57.6	0.402	-39.0
1000	0.182	-136.2	3.494	82.7	0.124	58.8	0.374	-38.9
1200	0.159	-153.3	2.988	76.9	0.142	59.6	0.359	-39.4
1400	0.147	-170.3	2.632	71.2	0.163	59.9	0.348	-40.7
1600	0.145	174.4	2.345	66.0	0.182	59.2	0.339	-43.2
1800	0.149	162.6	2.128	61.4	0.200	58.4	0.329	-46.3
2000	0.161	150.9	1.967	57.1	0.219	58.1	0.318	-49.5

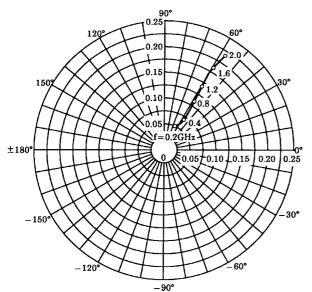
 $\begin{array}{l} S_{11e} \\ V_{CE} = 5V \\ I_{C} = 5mA \\ Ta = 25^{\circ}C \\ (UNIT:\Omega) \end{array}$

 S_{21e} $V_{CE} = 5V$ $I_{C} = 5mA$ $T_{a} = 25^{\circ}C$





 S_{12e} $V_{CE} = 5V$ $I_{C} = 5mA$ $T_{a} = 25^{\circ}C$



 S_{22e} $V_{CE} = 5V$ $I_{C} = 5mA$ $Ta=25^{\circ}C$ (UNIT : Ω) j50 j25 j100 j150 j10 j250 | [100 10 250 -j250 f = 0.2GHz, -j150 j100 _j50

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